



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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Group Art Unit: 2828
TECHNOLOGY CENTER 2800

In re the Application of: **Daijiro INOUE et al.**

Serial No.: **09/746,065**

Examiner: **Armando Rodriguez**

Filed: **December 26, 2000**

P.T.O. Confirmation No.: 1991

For: **SEMICONDUCTOR LASER DEVICE**

AMENDMENT UNDER 37 C.F.R. §1.111

Commissioner for Patents
Washington, D.C. 20231

6#/amdta

12/4/02

November 27, 2002

Al Brown

Sir:

In response to the Office Action dated May 28, 2002, extended to November 28, 2002 by a three month Petition for Extension of Time, please amend the above-identified application as follows:

IN THE CLAIMS:

~~Please~~ **cancel claims 4 and 27 - 33 without prejudice or disclaimer.**

Please amend claims 1, 2, 3, 5, 7, 17 and 24 as follows:

1. (Amended) A semiconductor laser device comprising:

an active layer;

a first cladding layer of a first conduction type provided on said active layer;

a current blocking layer of a second conduction type provided on said first cladding layer

except a current injection region;

a'